

## Features

- $BV_{CEO} > -45V$
- $I_C = -100mA$  Collector Current
- Epitaxial Planar Die Construction
- Ultra-Small Surface Mount Package
- Complementary NPN Type: BC847AT, BT, CT
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

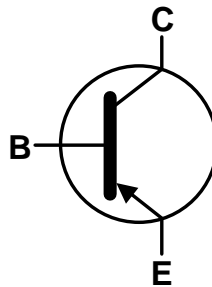
## Mechanical Data

- Case: SOT523
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208  $\text{e3}$
- Weight: 0.002 grams (Approximate)

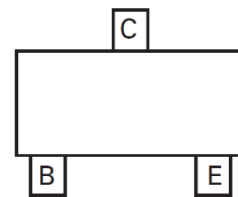


SOT523

Top View



Device Symbol



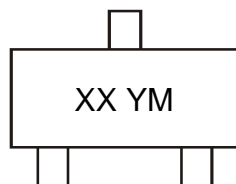
Pin-Out Top View

## Ordering Information (Note 4)

| Product     | Compliance | Marking | Reel Size (inches) | Tape Width (mm) | Quantity per Reel |
|-------------|------------|---------|--------------------|-----------------|-------------------|
| BC857AT-7-F | AEC-Q101   | 3V      | 7                  | 8               | 3,000             |
| BC857BT-7-F | AEC-Q101   | 3W      | 7                  | 8               | 3,000             |
| BC857CT-7-F | AEC-Q101   | 3G      | 7                  | 8               | 3,000             |

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

## Marking Information



XX = Product Type Marking Code  
 YM = Date Code Marking  
 Y or  $\bar{Y}$  = Year (ex: F = 2018)  
 M or  $\bar{M}$  = Month (ex: 9 = September)

### Date Code Key

| Year | 2018 | 2019 | 2020 | 2021 | 2022 | 2023 | 2024 | 2025 | 2026 | 2027 | 2028 |
|------|------|------|------|------|------|------|------|------|------|------|------|
| Code | F    | G    | H    | I    | J    | K    | L    | M    | N    | O    | P    |

| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
|-------|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| Code  | 1   | 2   | 3   | 4   | 5   | 6   | 7   | 8   | 9   | O   | N   | D   |

**Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic            | Symbol           | Value | Unit |
|---------------------------|------------------|-------|------|
| Collector-Base Voltage    | V <sub>CBO</sub> | -50   | V    |
| Collector-Emitter Voltage | V <sub>CEO</sub> | -45   | V    |
| Emitter-Base Voltage      | V <sub>EBO</sub> | -6    | V    |
| Collector Current         | I <sub>C</sub>   | -100  | mA   |

**Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                                   | Symbol                            | Value       | Unit |
|--------------------------------------------------|-----------------------------------|-------------|------|
| Power Dissipation (Note 5)                       | P <sub>D</sub>                    | 150         | mW   |
| Thermal Resistance, Junction to Ambient (Note 5) | R <sub>θJA</sub>                  | 833         | °C/W |
| Operating and Storage Temperature Range          | T <sub>J</sub> , T <sub>STG</sub> | -55 to +150 | °C   |

**ESD Ratings** (Note 6)

| Characteristic                             | Symbol  | Value | Unit | JEDEC Class |
|--------------------------------------------|---------|-------|------|-------------|
| Electrostatic Discharge – Human Body Model | ESD HBM | 4,000 | V    | 3A          |
| Electrostatic Discharge – Machine Model    | ESD MM  | 400   | V    | C           |

- Notes: 5. For a device mounted with the collector lead on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.  
 6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

**Thermal Characteristics and Derating Information**

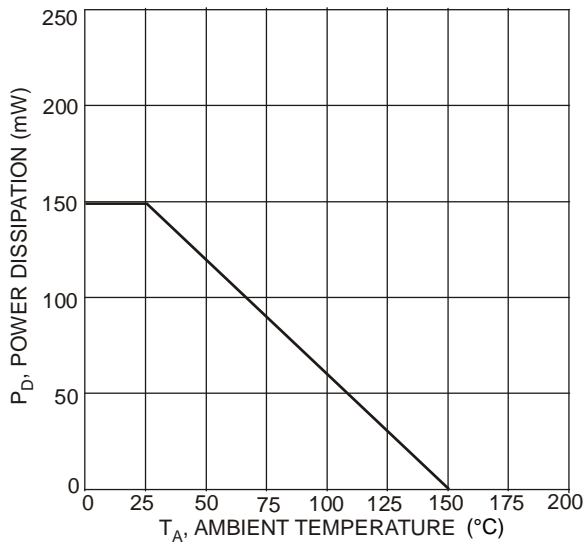


Fig. 1, Max Power Dissipation vs. Ambient Temperature

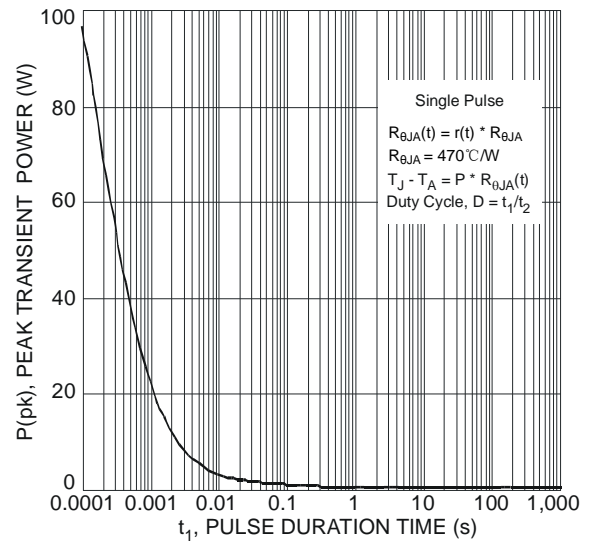


Fig. 2 Single Pulse Maximum Power Dissipation

**Thermal Characteristics and Derating Information (Cont.)**

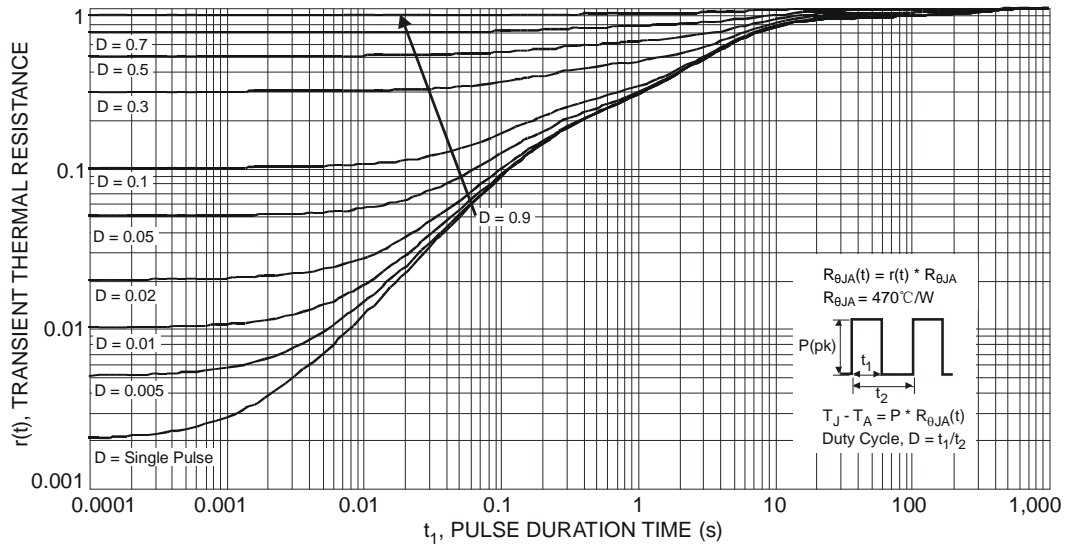


Fig. 3 Transient Thermal Response

**Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)**

| Characteristic                       | Symbol               | Min  | Typ          | Max          | Unit | Test Condition                                                                                    |
|--------------------------------------|----------------------|------|--------------|--------------|------|---------------------------------------------------------------------------------------------------|
| <b>OFF CHARACTERISTICS (Note 7)</b>  |                      |      |              |              |      |                                                                                                   |
| Collector-Base Breakdown Voltage     | BV <sub>CB0</sub>    | -50  | —            | —            | V    | I <sub>C</sub> = -100μA, I <sub>E</sub> = 0                                                       |
| Collector-Emitter Breakdown Voltage  | BV <sub>CEO</sub>    | -45  | —            | —            | V    | I <sub>C</sub> = -1mA, I <sub>B</sub> = 0                                                         |
| Emitter-Base Breakdown Voltage       | BV <sub>EBO</sub>    | -6   | —            | —            | V    | I <sub>E</sub> = -100μA, I <sub>C</sub> = 0                                                       |
| <b>ON CHARACTERISTICS (Note 7)</b>   |                      |      |              |              |      |                                                                                                   |
| DC Current Gain                      | Current Gain A       | 125  | —            | 250          | —    | V <sub>CE</sub> = -5V, I <sub>C</sub> = -2mA                                                      |
|                                      | B                    | 220  | 290          | 475          | —    |                                                                                                   |
|                                      | C                    | 420  | 520          | 800          | —    |                                                                                                   |
| Collector-Emitter Saturation Voltage | V <sub>CE(SAT)</sub> | —    | —            | -300<br>-650 | mV   | I <sub>C</sub> = -10mA, I <sub>B</sub> = -0.5mA<br>I <sub>C</sub> = -100mA, I <sub>B</sub> = -5mA |
| Base-Emitter Saturation Voltage      | V <sub>BE(SAT)</sub> | —    | -700<br>-900 | —            | mV   | I <sub>C</sub> = -10mA, I <sub>B</sub> = -0.5mA<br>I <sub>C</sub> = -100mA, I <sub>B</sub> = -5mA |
| Base-Emitter Voltage                 | V <sub>BE(ON)</sub>  | -600 | —            | -750<br>-820 | mV   | V <sub>CE</sub> = -5V, I <sub>C</sub> = -2mA<br>V <sub>CE</sub> = -5V, I <sub>C</sub> = -10mA     |
| Collector-Emitter Cutoff Current     | I <sub>CBO</sub>     | —    | —            | -15          | nA   | V <sub>CB</sub> = -30V                                                                            |
|                                      |                      | —    | —            | -4           | μA   | V <sub>CB</sub> = -30V, T <sub>A</sub> = +150°C                                                   |
| <b>SMALL SIGNAL CHARACTERISTICS</b>  |                      |      |              |              |      |                                                                                                   |
| Output Capacitance                   | C <sub>OBO</sub>     | —    | —            | 4.5          | pF   | V <sub>CB</sub> = -10V, f = 1MHz                                                                  |
| Current Gain-Bandwidth Product       | f <sub>T</sub>       | 100  | —            | —            | MHz  | V <sub>CE</sub> = -5V, I <sub>C</sub> = -10mA,<br>f = 100MHz                                      |
| Noise Figure                         | NF                   | —    | —            | 10           | dB   | I <sub>C</sub> = -0.2mA, V <sub>CE</sub> = -5V,<br>R <sub>S</sub> = 2kΩ, f = 1MHz,<br>BW = 200Hz  |

Note: 7. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

**Typical Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

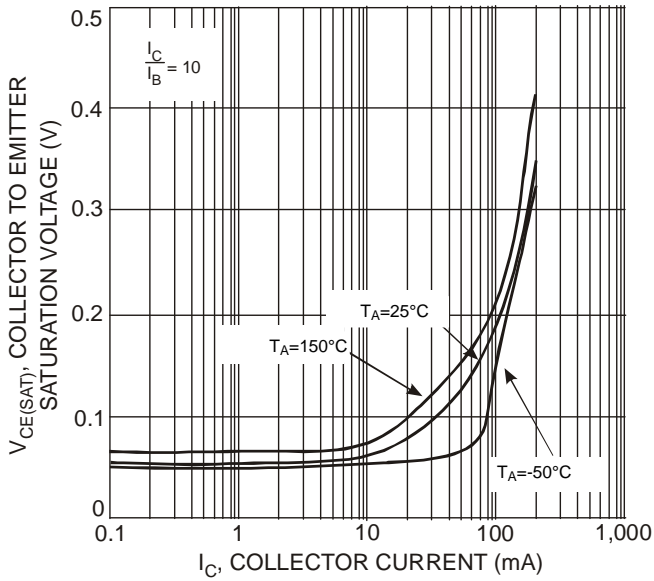


Fig. 2, Collector Emitter Saturation Voltage vs. Collector Current

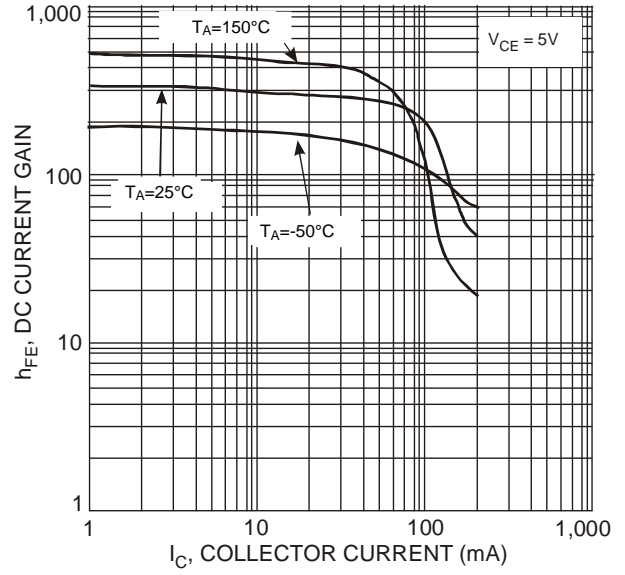


Fig. 3, DC Current Gain vs. Collector Current

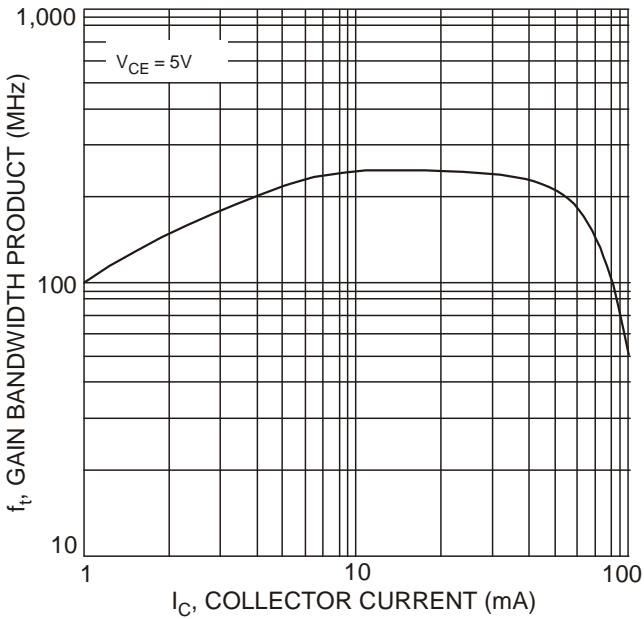
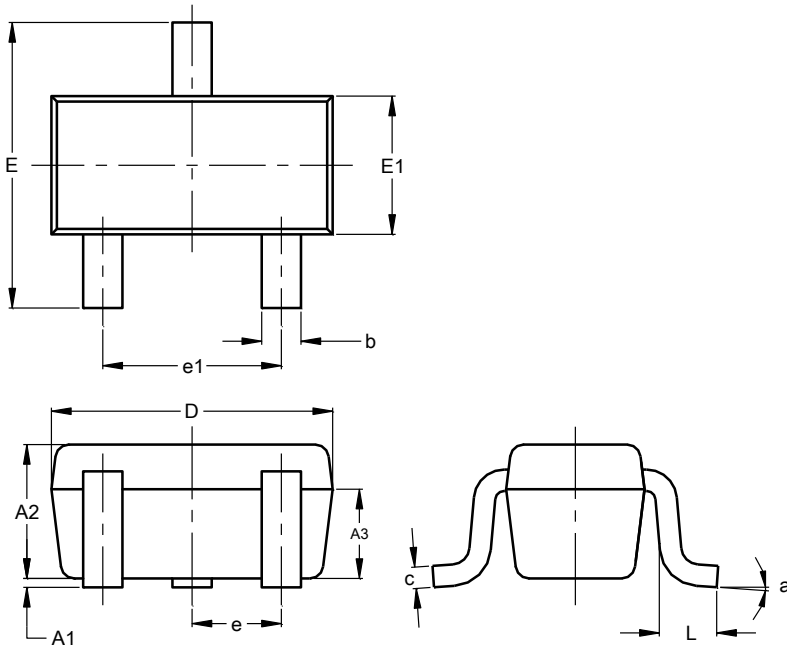


Fig. 4, Gain Bandwidth Product vs. Collector Current

**Package Outline Dimensions**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT523**



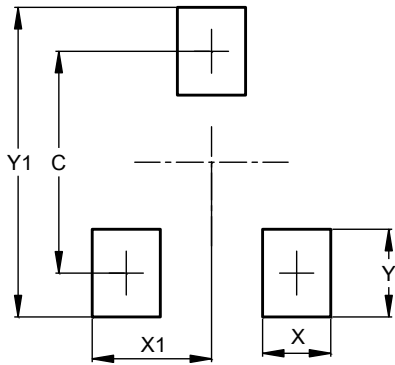
| SOT523 |          |      |      |
|--------|----------|------|------|
| Dim    | Min      | Max  | Typ  |
| A      | 0.60     | 0.80 | 0.75 |
| A1     | 0.00     | 0.10 | 0.05 |
| A3     | 0.45     | 0.65 | 0.50 |
| b      | 0.15     | 0.30 | 0.22 |
| c      | 0.10     | 0.20 | 0.12 |
| D      | 1.50     | 1.70 | 1.60 |
| E      | 1.45     | 1.75 | 1.60 |
| E1     | 0.75     | 0.85 | 0.80 |
| e      | 0.50 BSC |      |      |
| e1     | 0.90     | 1.10 | 1.00 |
| L      | 0.20     | 0.40 | 0.33 |
| a      | 0°       | --   | 8°   |

All Dimensions in mm

**Suggested Pad Layout**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT523**



| Dimensions | Value |
|------------|-------|
| C          | 1.29  |
| X          | 0.40  |
| X1         | 0.70  |
| Y          | 0.51  |
| Y1         | 1.80  |

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